

# Lead thickness required to shield synchrotron radiation experiments



## *Numquam ponenda est pluralitas sine necessitate*

Plurality must never be posited without necessity

We know:

A 'target' is in the beam

The mechanisms of production of secondary radiation (fluorescence, scattering (pp))

Properties of the shielding (lead)

Number of photons as function of energy (source, optics)

The geometry of the enclosure

We don't know:

The composition of the target (air, slits, sample)

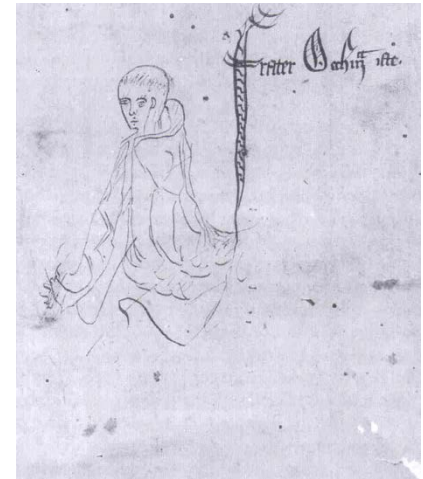
The geometry of the target (angle of incidence)

The position of the target along the beam

We want to know:

The required lead thickness

Worst cases (conditions for a survey)



1287-1347

# Generation of secondary radiation

## Secondary photons from a thick target

$$n = n_0 (Z r_e^2 C_{KN} + \sigma_\alpha + \sigma_\beta) / (A u) / (\mu_S / \rho_S)$$

$n_0$ : incoming photons of energy  $E_0$

$\sigma_\alpha(Z)$ ,  $\sigma_\beta(Z)$ : fluorescence cross section

$$E_\alpha < E_\beta < E_0$$

**M. O. Krause, C. W. Nestor, C. J. Sparks, E. Ricci.** *X-Ray Fluorescence Cross Sections for K and L X Rays of the Elements*. Oak Ridge, Tennessee : Oak Ridge National Laboratory, 1978

$C_{KN}$  Klein-Nishina scattering cross section

$$C_{KN}(E_0, \theta) < 1, E_S < E_0$$

$r_e$  classical electron radius,  $A$  atomic mass number,  $u$  atomic mass

$\mu_S / \rho_S$  mass attenuation coefficient of the target



Attenuation by shielding

$$I = I_0 (e^{-\mu_H t_{eff}})$$

Absorption in the dose object

$$D = n E_S (1 - \exp(-\mu_T L_0)) (\mu_E / \mu_T) / \rho_D a L_0$$

$\mu_E, \mu_T$  energy and total absorption coefficient,  $\rho_D, a L_0$  density and volume

Dose due to secondary radiation (surface)

$$D = \frac{n E_S \mu_E}{\rho_D \pi r^2} = n_0 E_S \frac{Z r_e^2 C_{KN} + \sigma_\alpha + \sigma_\beta}{A u \pi r^2} \frac{\mu_E / \rho_D}{\mu_S / \rho_S} e^{-\mu_H t_{eff}}$$



# Required shielding thickness

$$\mu_H t_{\text{eff}} > \ln\left(\dot{n}_0 E_S \frac{\mu_E / \rho_D}{\mu_S / \rho_S} \frac{Z r_e^2 C_{KN} + \sigma_\alpha + \sigma_\beta}{A u \pi r^2 \dot{D}}\right)$$

$$\mu_H t_{\text{eff}} > \ln \dot{N}_0 E_S / (\pi \dot{D} A u) + \ln[(\mu_E / \rho_D) / (\mu_S / \rho_S)] + \ln (Z r_e^2 C_{KN} + \sigma_\alpha + \sigma_\beta) / r^2$$

$$\dot{D} < 0.5 \mu\text{Sv/h design goal, } (\mu_E / \rho_D) / (\mu_S / \rho_S) < 1$$

in practical units:

$$\mu_H t_{\text{eff}} > \ln \dot{n}_0 [\text{s}^{-1}] + \ln E_S [\text{keV}] + \ln(0.08 Z C_{KN} + \sigma_\alpha [\text{b}] + \sigma_\beta [\text{b}]) - \ln(A) - 2 \ln(r [\text{m}]) - 17.63$$

At low energies (neglecting scattering, or adding it to  $\sigma_\beta$ )

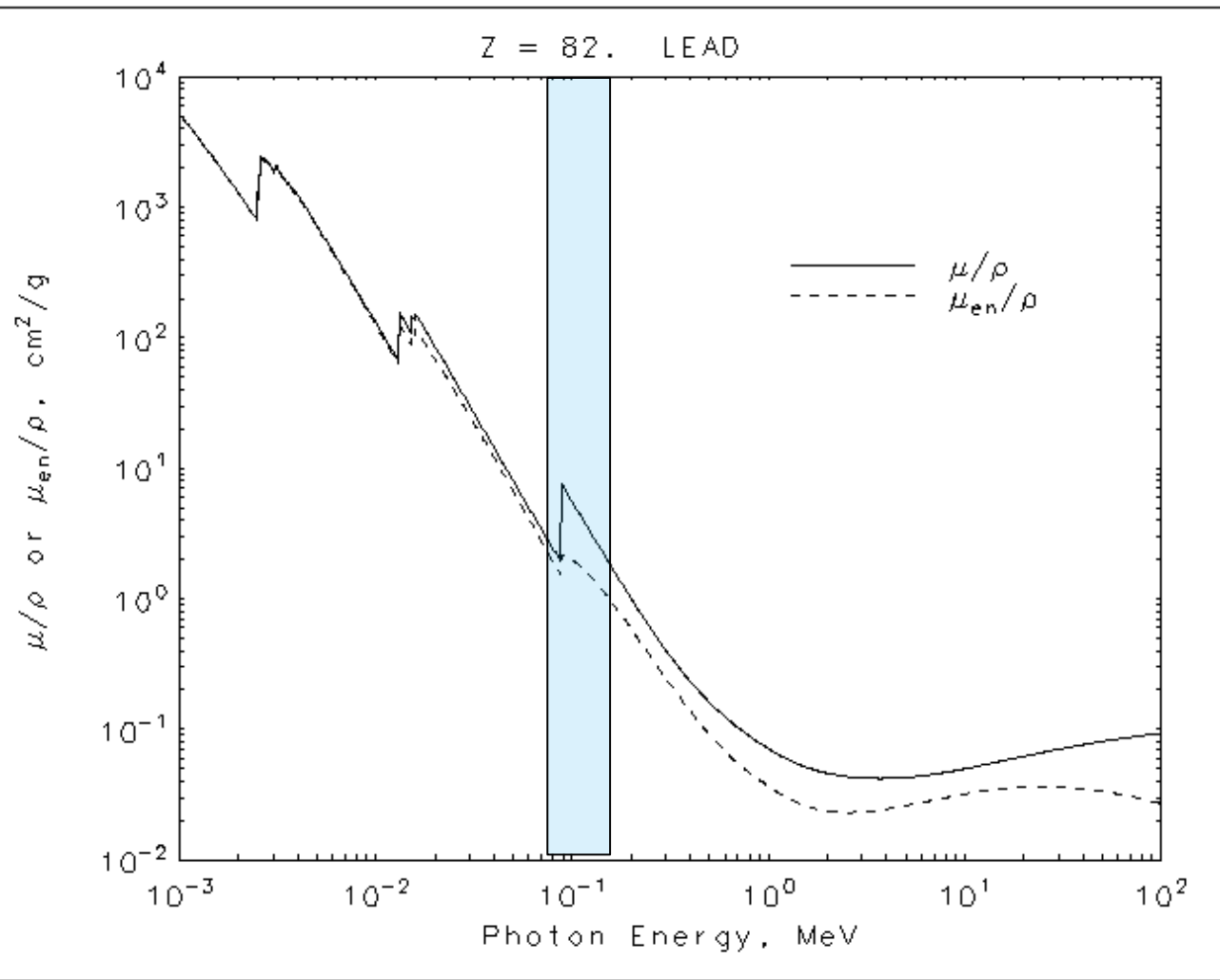
$$\mu_H t_{\text{eff}} > \ln \dot{n}_0 [\text{s}^{-1}] + \ln E_S [\text{keV}] + \ln(0.08 Z + \sigma_\alpha [\text{b}] + \sigma_\beta [\text{b}]) - \ln(A) - 2 \ln(r [\text{m}]) - 17.63$$

At high energies (neglecting fluorescence,  $A/Z \geq 2$ )

$$\mu_H t_{\text{eff}} > \ln \dot{n}_0 [\text{s}^{-1}] + \ln E_S [\text{keV}] + \ln(Z C_{KN}) - 2 \ln(r [\text{m}]) - 20.85$$



# Absorption in lead



| E[MeV]       | $\mu/\rho$ [cm <sup>2</sup> /g] |
|--------------|---------------------------------|
| 2.00000E-02  | 8.636E+01                       |
| 3.00000E-02  | 3.032E+01                       |
| 4.00000E-02  | 1.436E+01                       |
| 5.00000E-02  | 8.041E+00                       |
| 6.00000E-02  | 5.021E+00                       |
| 8.00000E-02  | 2.419E+00                       |
| 8.80045E-02  | 1.910E+00                       |
| K8.80045E-02 | 7.683E+00                       |
| 1.00000E-01  | 5.549E+00                       |
| 1.50000E-01  | 2.014E+00                       |
| 2.00000E-01  | 9.985E-01                       |
| 3.00000E-01  | 4.031E-01                       |
| 4.00000E-01  | 2.323E-01                       |
| 5.00000E-01  | 1.614E-01                       |
| 6.00000E-01  | 1.248E-01                       |
| 8.00000E-01  | 8.870E-02                       |
| 1.00000E+00  | 7.102E-02                       |

Seltzer, J. H. Hubbel and S. M. *Tables of X-Ray Mass Attenuation Coefficients*. NIST. 1989.

<http://www.nist.gov/pml/data/xraycoef/>



# The standard undulator @ P22

$$\mu_H t_{\text{eff}} > \ln n_0 [\text{s}^{-1}] + \ln E_S [\text{keV}] + \ln(0.08Z + \sigma_\alpha [\text{b}] + \sigma_\beta [\text{b}]) - \ln(A) - 2 \ln(r [\text{m}]) - 17.63$$

Fluorescence dominates below ~150keV

| $\dot{N}_0 [\text{s}^{-1}]$ | E[keV] | Element | A      | Z  | $\sigma_\alpha [\text{b}]$ | $\sigma_\beta [\text{b}]$ | $\mu_\beta [\text{cm}^2/\text{g}]$ | $1/\rho\mu_\beta [\text{mm}]$ | r [m] | $N_{\text{att}}$ | t [mm] | hkl |
|-----------------------------|--------|---------|--------|----|----------------------------|---------------------------|------------------------------------|-------------------------------|-------|------------------|--------|-----|
| 4,22E+13                    | 30     | Sb      | 121,76 | 51 | 4710                       | 880                       | 30,32                              | 0,0300                        | 1     | 19,16            | 0,574  | 111 |
| 1,58E+12                    | 53     | Tb      | 158,93 | 65 | 2719                       | 549                       | 8,1                                | 0,1122                        | 1     | 15,71            | 1,763  | 111 |
| 3,30E+12                    | 90     | Pb      | 207,2  | 82 | 1460                       | 310                       | 1,91                               | 0,4760                        | 1     | 16,15            | 7,686  | 111 |
| 1,44E+12                    | 90     | Pb      | 207,2  | 82 | 1460                       | 310                       | 1,91                               | 0,4760                        | 1     | 15,32            | 7,291  | 220 |
| 6,93E+11                    | 90     | Pb      | 207,2  | 82 | 1460                       | 310                       | 1,91                               | 0,4760                        | 1     | 14,59            | 6,943  | 311 |
| 2,23E+11                    | 90     | Pb      | 207,2  | 82 | 1460                       | 310                       | 1,91                               | 0,4760                        | 1     | 13,45            | 6,404  | 333 |

$E_S$  replaced by  $E=E_0$

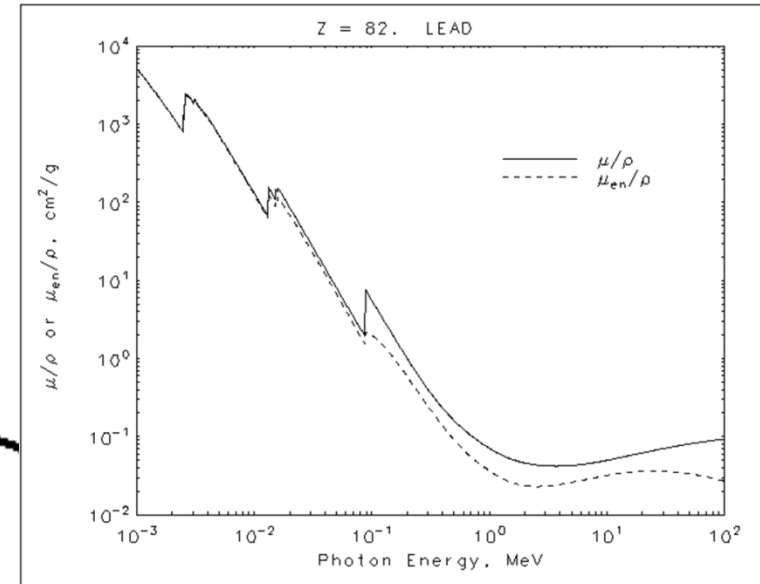
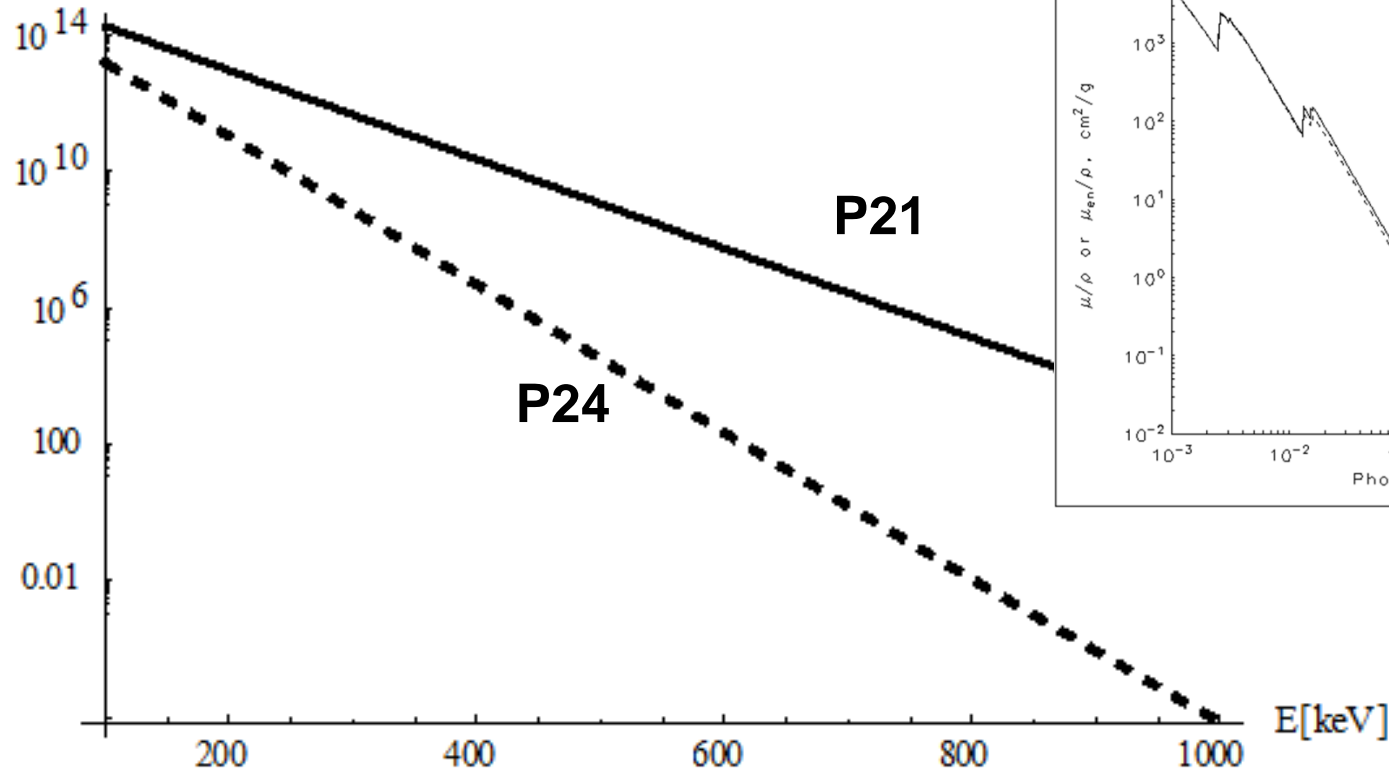
With the thickness required to shield against  $\beta$  fluorescence (and scattering) the contribution of  $\alpha$  fluorescence (lower energy and therefore stronger attenuation but higher cross section) is calculated (same spread sheet, but not shown here).

Depending on this result the thickness has to be increased.



# High energies

$I[\text{phot} / \text{sec} / 0.1 \% dE / E]$

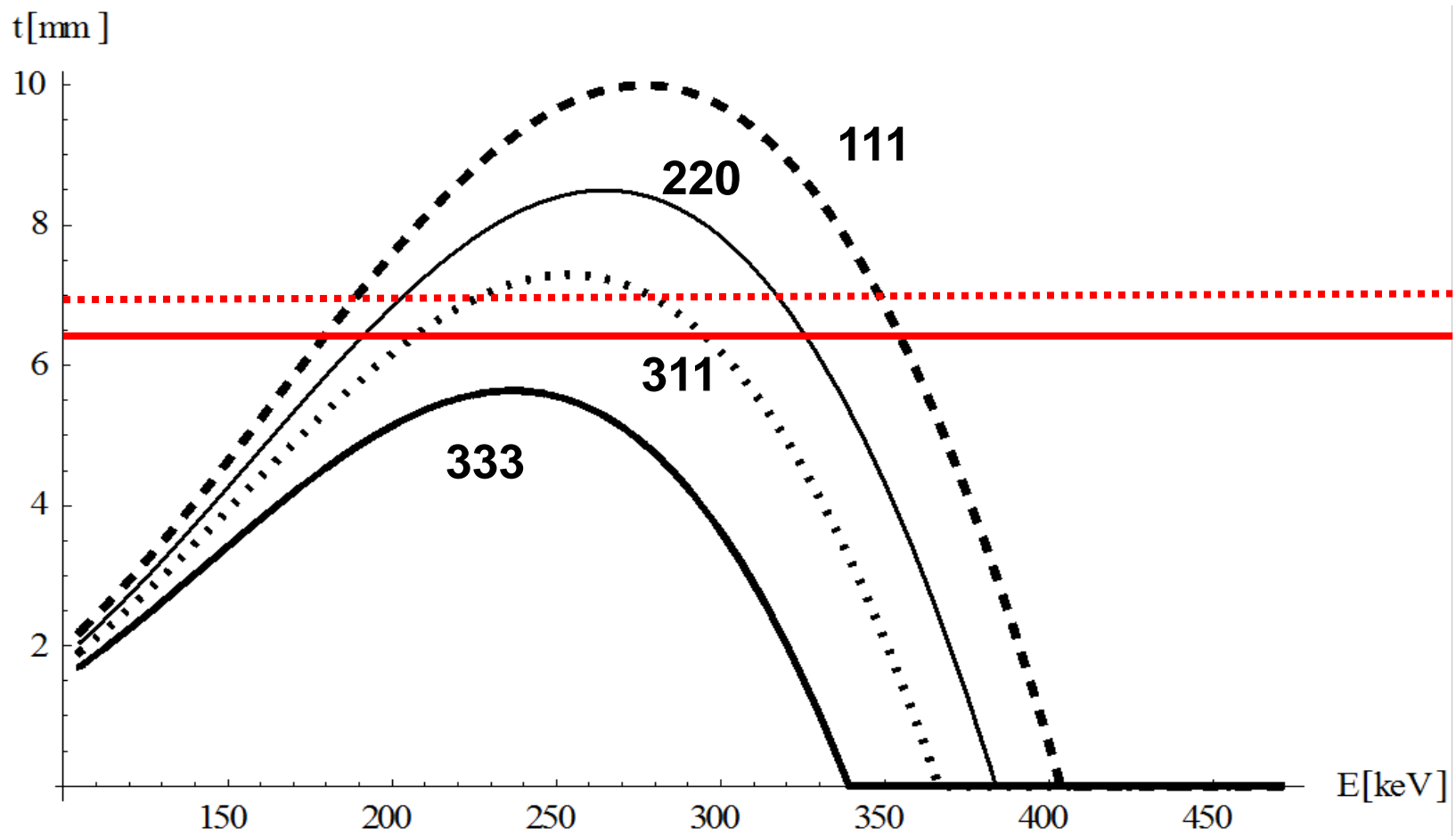


*Photon flux as function of energy for the standard undulator (dashed) and the W45 wiggler at the P21 beam line showing exponential decay.*





# Standard undulator



$$C_{KN}(E_0, \theta) = 1, E_S = E_0 \text{ (forward scattering)}$$



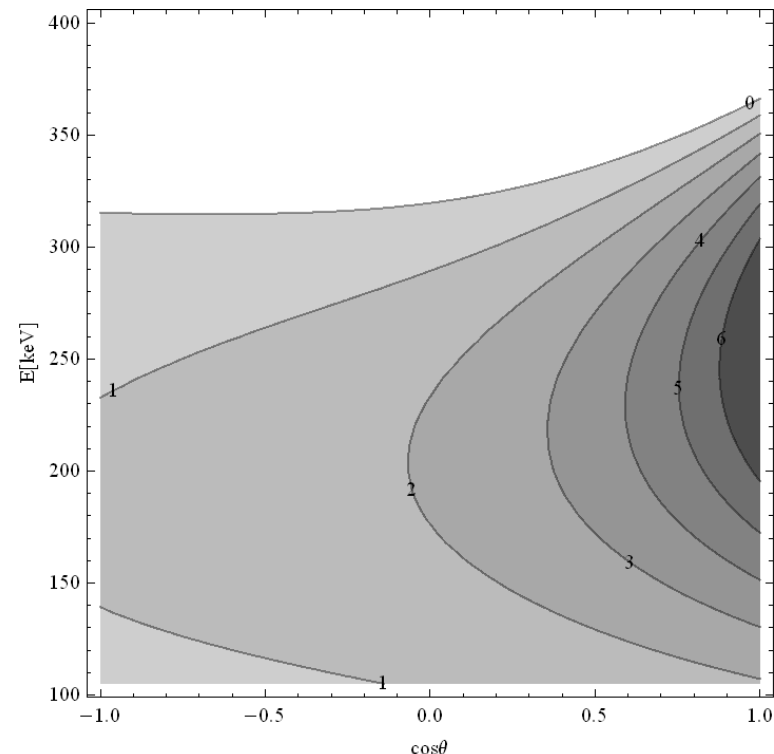
# High energy scattering

$$C_{KN} = \frac{(1 + \cos^2 \theta) \left\{ 1 + \frac{\epsilon^2 (1 - \cos(\theta))^2}{(1 + \epsilon(1 - \cos \theta))(1 + \cos^2 \theta)} \right\}}{2(1 + \epsilon[1 - \cos \theta])^2}$$

$$\epsilon = E_0 / mc^2$$

$$E_S = E_0 / (1 + \epsilon(1 - \cos \theta))$$

Both, cross section and secondary energy depend only on incoming energy and scattering angle



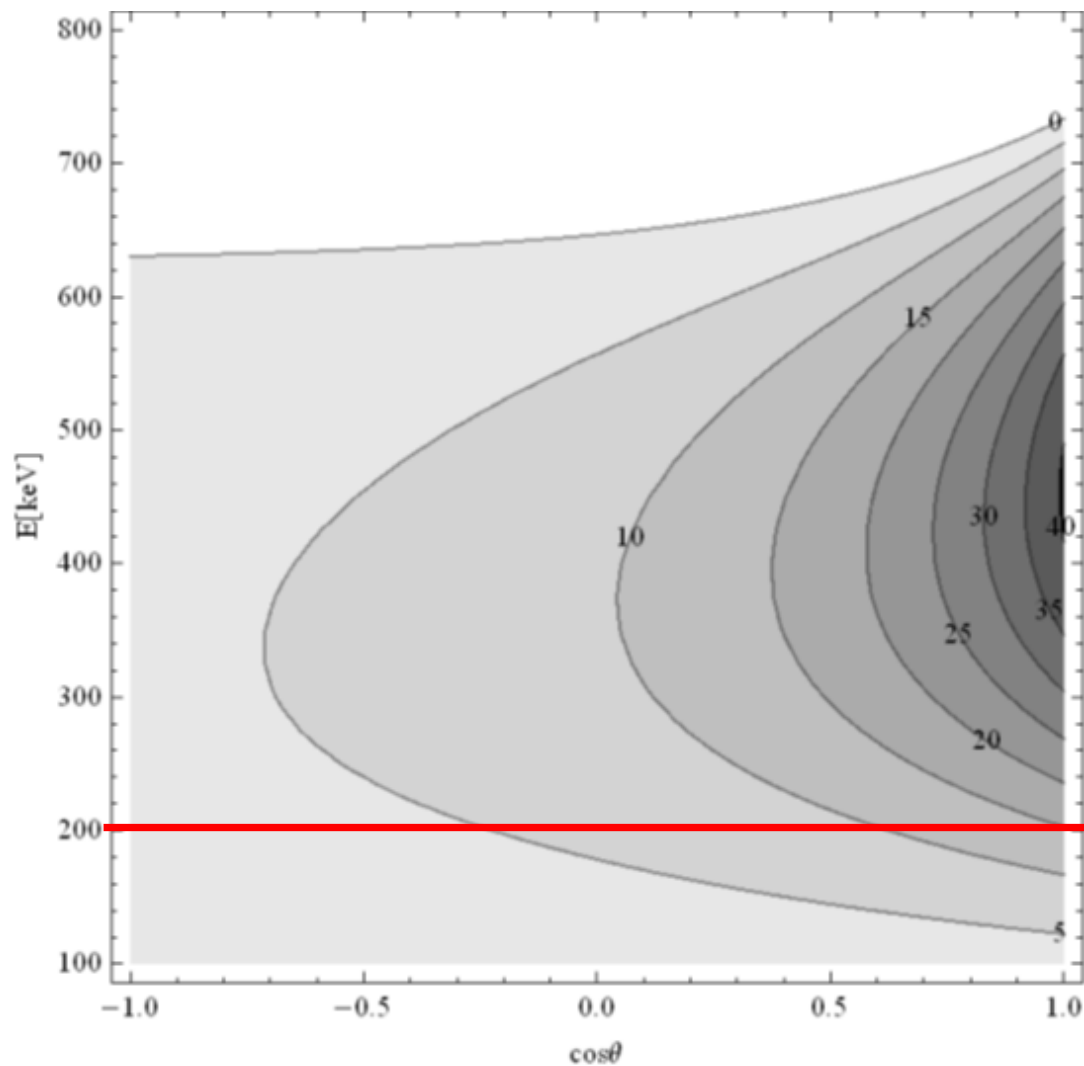
Required lead thickness to shield against scattered radiation (311 reflection @ P24)

# High energy wiggler W45 @ P21

To shield against lead fluorescence a thickness of 11 mm (distance to target 1m) respectively 10 mm (distance 2m) would be required (assuming an ideal 111 mosaic DCM). Shielding against scattering would far exceed these thicknesses.

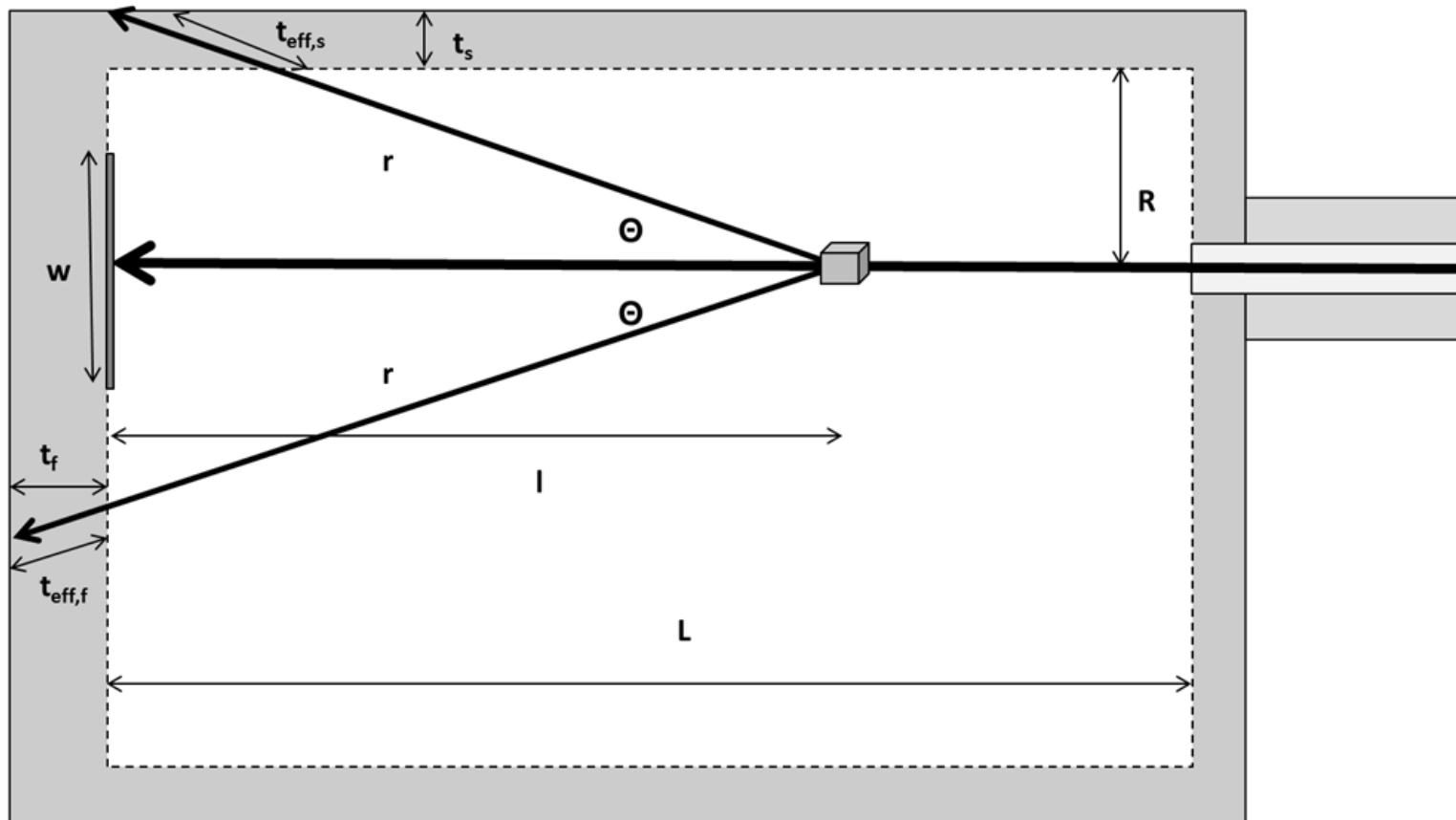
Therefore it was decided to limit the energy range (travel range of monochromator crystals).

The third harmonic (333 reflection) has three times higher energy but about thirty times lower intensity.



# Geometry of the experiment

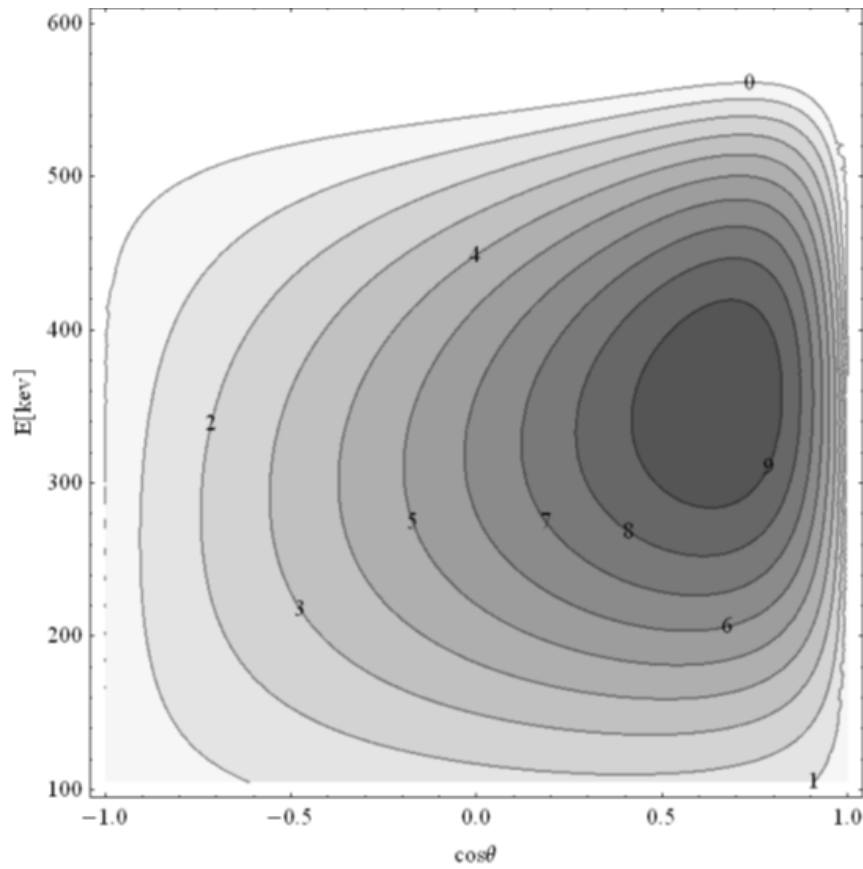
Up to now no assumptions about the scattering geometry have been required. Except that the target is in the beam.



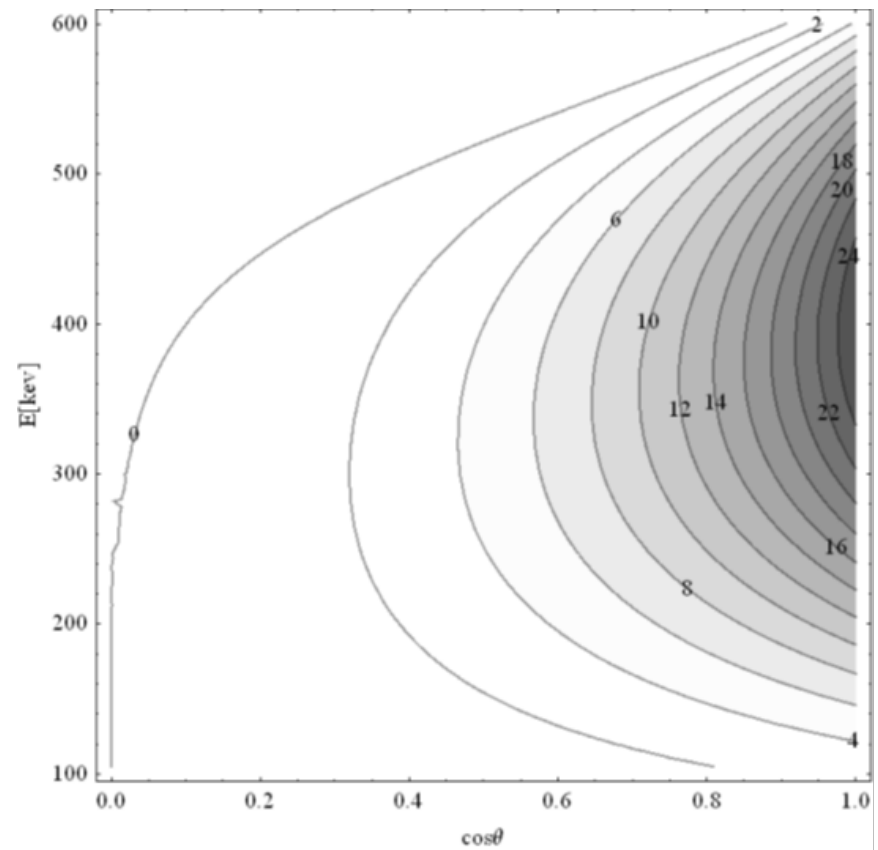
$$t_{eff,s} = t_s / \sin\theta \quad t_{eff,f} = t_f / \cos\theta \quad r_s = R / \sin\theta \quad r_f = l / \cos\theta \quad r_b = (L-l) / \cos\theta$$



# 3rd harmonic (333) @ P21



Thickness of sidewall below 10mm  
(distance 1m)

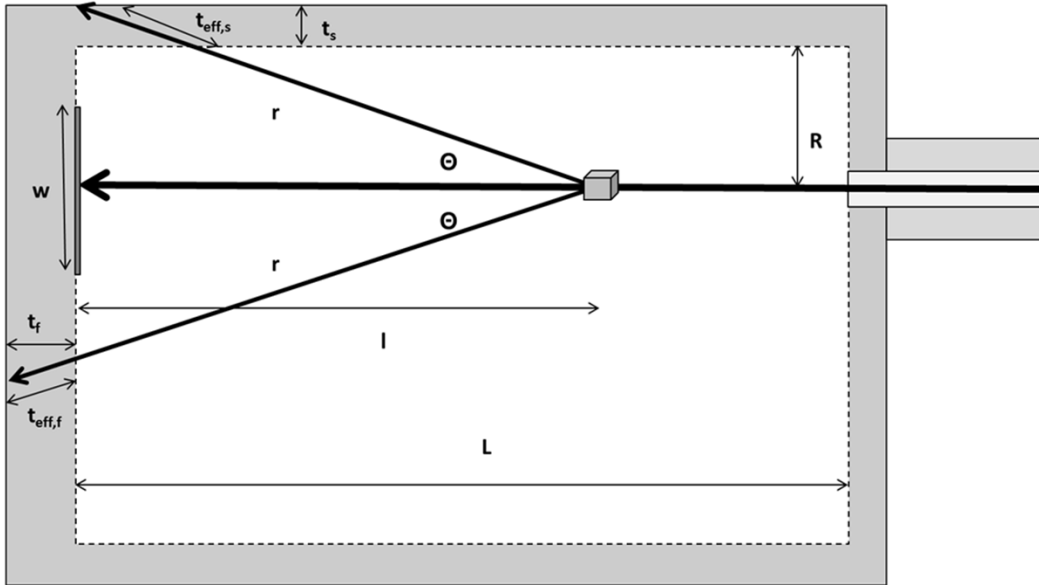


Thickness of front wall up to 25 mm  
(forward direction, distance 1m)

# Front wall & survey

$$\cos\theta = l / \sqrt{l^2 + \left(\frac{w}{2}\right)^2}$$

$$2\ln r = \ln\left(l^2 + \left(\frac{w}{2}\right)^2\right)$$



**P21:**

$t=25$  mm ( $0.7\text{m} < w < 1.6\text{m}$ )

$t=20$  mm ( $w > 1.6\text{m}$ )

$$t > t_a l / \sqrt{l^2 + \left(\frac{w}{2}\right)^2} * [\ln(\dot{n}_0 E_S) + \ln C_{KN} - \ln\left(l^2 + \left(\frac{w}{2}\right)^2\right) + \ln(r_e^2 / 2\pi u \dot{D})]$$

$$= l / \sqrt{l^2 + \left(\frac{w}{2}\right)^2} \left( (t_{eff,max} - t_{a,max} \left( \ln\left(l^2 + \left(\frac{w}{2}\right)^2\right) \right) \right)$$

$$t_a = 1/\mu_H$$

Given  $w$ , we can calculate  $t$  as function of  $l$  and determine the worst case yielding the target position for a survey

# Summary

- > A simple calculus has been developed based on the (known) properties of source, optics, shielding material and the fundamental interaction mechanisms (fluorescence and scattering).
- > Below  $\sim 150$  keV (isotropic) fluorescence dominates and calculations can be performed using a simple spread sheet
- > For higher energies scattering has to be taken into account
- > If required the anisotropy of scattering is used to optimize the shielding thickness
- > From the calculations also the (worst case) conditions for a survey can be determined



I want to thank **DESY-FS**

especially Markus Tischer (calculation of spectra using PHOTON) and Ulrich Lienert (calculation of reflectivity of curved (mosaic) crystal monochromators)



## for your attention

### Round robin

### Handbook